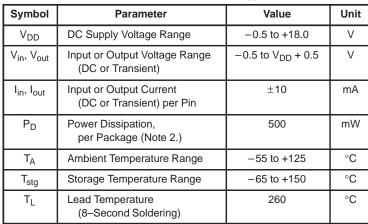
128-Bit Static Shift Register

The MC14562B is a 128-bit static shift register constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. Data is clocked in and out of the shift register on the positive edge of the clock input. Data outputs are available every 16 bits, from 16 through bit 128. This complementary MOS shift register is primarily used where low power dissipation and/or high noise immunity is desired.

- Diode Protection on All Inputs
- Fully Static Operation
- Cascadable to Provide Longer Shift Register Lengths
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range



MAXIMUM RATINGS (Voltages Referenced to V_{SS}) (Note 1.)

Maximum Ratings are those values beyond which damage to the device 1. may occur.

2. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



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MARKING DIAGRAMS



MC14562BCP AWLYYWW 1

= Assembly Location Α WL or L = Wafer Lot YY or Y = Year WW or W = Work Week

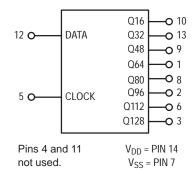
ORDERING INFORMATION

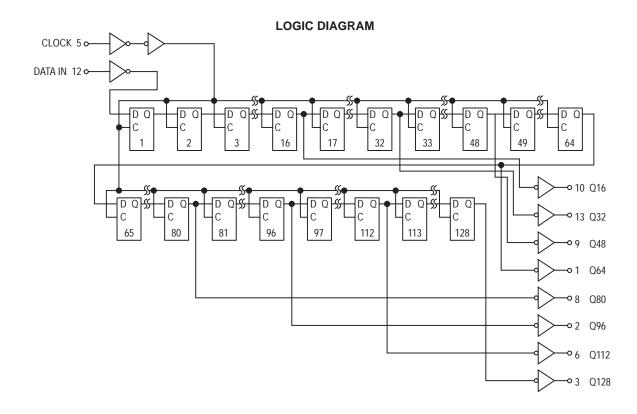
Device	Package	Shipping		
MC14562BCP	PDIP-14	25/Rail		

PIN ASSIGNMENT

Q64 [1•	14	D V _{DD}			
Q96 [2	13	Q32			
Q128 [3	12	data			
NC [4	11	D NC			
сгоск [5	10	Q16			
Q112 [6	9	Q48			
v _{ss} D	7	8	080			
NC = NO CONNECTION						

BLOCK DIAGRAM





			V _{DD}	– 55°C			25°C		125°C		
Characteristic	;	Symbol	Vdc	Min	Max	Min	Тур ^(3.)	Max	Min	Мах	Unit
Output Voltage V _{in} = V _{DD} or 0	"0" Level	V _{OL}	5.0 10 15		0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05		0.05 0.05 0.05	Vdc
$V_{in} = 0 \text{ or } V_{DD}$	"1" Level	V _{OH}	5.0 10 15	4.95 9.95 14.95		4.95 9.95 14.95	5.0 10 15		4.95 9.95 14.95		Vdc
Input Voltage $(V_O = 4.5 \text{ or } 05 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$	"0" Level)	V _{IL}	5.0 10 15		1.5 3.0 4.0		2.25 4.50 6.75	1.5 3.0 4.0		1.5 3.0 4.0	Vdc
$(V_{O} = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_{O} = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_{O} = 1.5 \text{ or } 13.5 \text{ Vdc})$	"1" Level)	V _{IH}	5.0 10 15	3.5 7.0 11		3.5 7.0 11	2.75 5.50 8.25		3.5 7.0 11		Vdc
$\begin{array}{l} \text{Output Drive Current} \\ (V_{OH} = 2.5 \ \text{Vdc}) \\ (V_{OH} = 4.6 \ \text{Vdc}) \\ (V_{OH} = 9.5 \ \text{Vdc}) \\ (V_{OH} = 13.5 \ \text{Vdc}) \end{array}$	Source	I _{OH}	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	 	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	 	- 1.7 - 0.36 - 0.9 - 2.4	 	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I _{OL}	5.0 10 15	0.64 1.6 4.2		0.51 1.3 3.4	0.88 2.25 8.8		0.36 0.9 2.4		mAdc
Input Current		l _{in}	15	—	±0.1	-	±0.00001	±0.1	—	±1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	_	_	_	-	5.0	7.5	_	_	pF
Quiescent Current (Per Package)		I _{DD}	5.0 10 15		5.0 10 20		0.010 0.020 0.030	5.0 10 20		150 300 600	μAdc
Total Supply Current ^{(4.) (4} (Dynamic plus Quiesc Per Package) (C _L = 50 pF on all out buffers switching)	ent,	ΙŢ	5.0 10 15		<u> </u>	I _T = (3	.94 μA/kHz) .81 μA/kHz) .52 μA/kHz)	f + I _{DD}			μAdc

Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.

5. To calculate total supply current at loads other than 50 pF:

 $I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$

where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and k = 0.004.

SWITCHING CHARACTERISTICS (6.) (CL = 50 pF, TA = 25 $^{\circ}\mathrm{C}$)

Characteristic	Symbol	V _{DD}	Min	Тур ^(7.)	Max	Unit
Output Rise and Fall Time t_{TLH} , $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ t_{TLH} , $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ t_{TLH} , $t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t _{TLH} , t _{THL}	5.0 10 15		100 50 40	200 100 80	ns
Propagation Delay Time Clock to Q t_{PLH} , $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 515 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 217 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 145 \text{ ns}$	t _{PLH} , t _{PHL}	5.0 10 15		600 250 170	1200 500 340	ns
Clock Pulse Width (50% Duty Cycle)	t _{WH}	5.0 10 15	600 220 150	300 110 75		ns
Clock Pulse Frequency	f _{cl}	5.0 10 15		1.9 5.6 8.0	1.1 3.0 4.0	MHz
Data to Clock Setup Time	t _{su(1)}	5.0 10 15	- 20 - 10 0	- 170 - 64 - 60		ns
	t _{su(0)}	5.0 10 15	- 20 - 10 0	- 91 - 58 - 48		ns
Data to Clock Hold Time	t _{h(1)}	5.0 10 15	350 165 155	263 109 100		ns
	t _{h(0)}	5.0 10 15	350 200 140	267 140 93		ns
Clock Input Rise and Fall Times	t _r , t _f	5.0 10 15			15 5 4	μs

6. The formulas given are for the typical characteristics only at 25°C.
7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

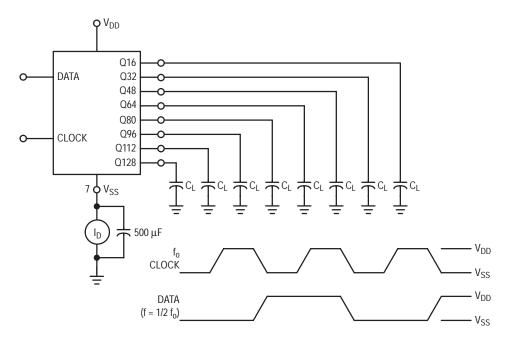
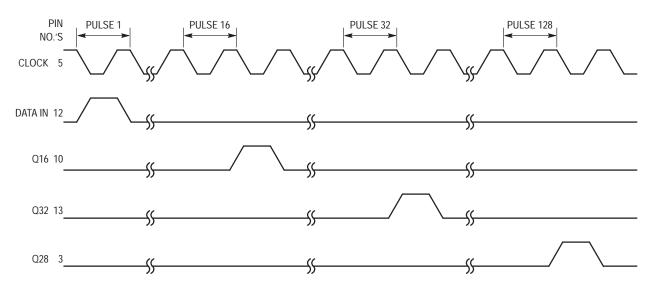
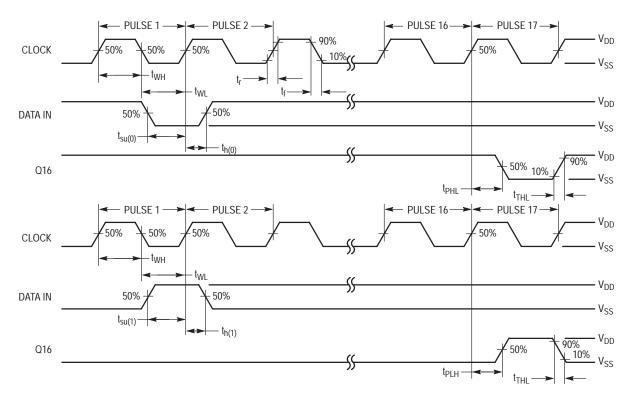


Figure 1. Power Dissipation Test Circuit and Waveforms

TIMING DIAGRAM

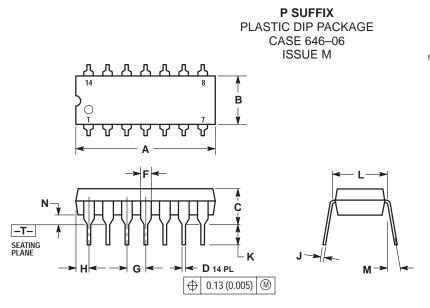


AC TEST WAVEFORMS



NOTE: The remaining Data–Bit Outputs (Q32, Q48, Q64, Q80, Q96, Q112 and Q128) will occur at Clock Pulse 32, 48, 64, 80, 96, 112, 128 in the same relationship as Q16.

PACKAGE DIMENSIONS



NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	18.80	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
К	0.115	0.135	2.92	3.43	
L	0.290	0.310	7.37	7.87	
Μ		10°		10°	
Ν	0.015	0.039	0.38	1.01	

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